

Note:

- i. **Part - A** should be answered in OMR sheet within first 40 minutes and OMR sheet should be handed over to hall invigilator at the end of 40 minutes.
 ii. **Part - B** and **Part - C** should be answered in answer booklet.

Time: 3 Hours**Max. Marks: 100****Part - A (20 × 1 Marks = 20 Marks)**

Marks BL CO

Answer All Questions

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|---|--|---|---|---|
| 1. Which among the following range of wavelengths is termed the optical C band?
(A) 1260 – 1360 nm
(C) 1530 – 1565 nm | (B) 1460 – 1530 nm
(D) 1625 – 1675 nm | 1 | 1 | 1 |
| 2. Assume a glass rod surrounded by air. If the refractive index, n_1 of the glass rod equals 1.6 and n_2 equals 1, then the critical angle is
(A) 28.5°
(C) 40.5° | (B) 38.68°
(D) 42.58° | 1 | 3 | 1 |
| 3. When three wave components co-propagate at angular frequency ω_1 , ω_2 , ω_3 , then a new wave is generated at frequency ω_4 , which is given by _____
(A) $\omega_4 = \omega_1 - \omega_2 - \omega_3$
(C) $\omega_4 = \omega_1 + \omega_2 - \omega_3$ | (B) $\omega_4 = \omega_1 + \omega_2 + \omega_3$
(D) $\omega_4 = \omega_1 - \omega_2 + \omega_3$ | 1 | 2 | 1 |
| 4. In fusion splicing, the splice losses typically are in the range of
(A) 0.05 – 0.10 dB
(C) 0.07 – 0.2 dB | (B) 0.1 – 0.2 dB
(D) 0.2 – 0.5 dB | 1 | 1 | 1 |
| 5. Carrier Confinement in LED structure is achieved through _____ of adjacent layers
(A) Difference in Refractive index
(C) Difference in width | (B) Difference in Bandgap
(D) Difference in doping concentration | 1 | 1 | 2 |
| 6. In LCD, molecules are arranged parallel to each other in _____ orientation.
(A) Nematic
(C) Smectic | (B) Cholestric
(D) Dipole | 1 | 1 | 2 |
| 7. When excitation arises because of bombardment of electrons is called as _____
(A) Electroluminescence
(C) Photoluminescence | (B) Cathodoluminescence
(D) Phosphorescence | 1 | 1 | 2 |
| 8. Determine the internal quantum efficiency generated within a device when it has a radiative recombination lifetime of 80 ns and total carrier recombination lifetime of 40 ns.
(A) 20
(C) 30 | (B) 50
(D) 40 | 1 | 3 | 2 |
| 9. What will be the responsivity of a Germanium PIN Photodiode at 1300nm?
(A) 0.45A/W
(C) 0.9A/W | (B) 0.65A/W
(D) 0.8A/W | 1 | 1 | 3 |

10.	_____ is the photodiode circuit bandwidth with $C_T=5\text{pF}$ and $R_T=2\text{k}\Omega$	1	1	3
	(A) 15.9MHz (B) 62MHz			
	(C) 628MHz (D) 159MHz			
11.	Compute the photocurrent of RAPD having multiplication factor of 36.7 and output current of $7\mu\text{A}$.	1	3	3
	(A) $0.01\mu\text{A}$ (B) $0.07\mu\text{A}$			
	(C) $0.54\mu\text{A}$ (D) $0.9\mu\text{A}$			
12.	_____ measures optical power as a function of wavelength	1	1	3
	(A) Optical Spectrum Analyser (B) Optical power attenuator			
	(C) Optical power meter (D) Optical time domain reflectometer			
13.	Which effect induces a strain and change in refractive index in optoelectronics?	1	2	4
	(A) Kerr effect (B) Pockels effect			
	(C) Photoelastic effect (D) Applied magnetic field			
14.	What is the technique used to bond and fabricate optoelectronics and electronic components?	1	1	4
	(A) Monolithic integration (B) Hybrid integration			
	(C) CMOS Technology (D) NMOS technology			
15.	For a optical modulator, if there is no presence of mismatch between the phases, the mismatch is represented as,	1	1	4
	(A) $\Delta\beta=\infty$ (B) $\Delta\beta=1$			
	(C) $\Delta\beta=-1$ (D) $\Delta\beta=0$			
16.	What is the condition to be satisfied for Bragg's regime?	1	1	4
	(A) $L \gg \lambda/\lambda$ (B) $L = \lambda/8/\lambda$			
	(C) $L \ll \lambda/2/\lambda$ (D) $L \gg \lambda/2/\lambda$			
17.	Which method determines the dispersion limitation of an optical link?	1	1	5
	(A) Link power budget (B) Rise time budget			
	(C) Fall time budget (D) Link and rise budget			
18.	Faraday rotator is used in _____	1	1	5
	(A) Mach Zehnder Interferometer (B) Fabry Perot Filter			
	(C) Isolator (D) Directional Couplers			
19.	_____ couplers divide the power equally	1	2	5
	(A) 3 dB (B) 6 dB			
	(C) 9 dB (D) 12 dB			
20.	The function of wavelength-division multiplexer is to _____	1	2	5
	(A) Separate signals at different wavelengths and couple them to different detectors. (B) Combine signals at different wavelengths to pass through a single fiber.			
	(C) Tap off part of the energy of the incoming signal. (D) Change the transmission speed of the input signal.			

Part - B (5 × 4 Marks = 20 Marks)

Answer any 5 Questions

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21.	A manufacturer wishes to make a silica core step index fiber with $V=75$ & $NA=0.3$ to be used at 820nm. If $n_1=1.458$, determine core radius & cladding index.	4	3	1
22.	Draw the amplification mechanism of the Erbium Doped Fiber Amplifier with the help of an energy level diagram.	4	2	2
23.	A silicon photodiode has a quantum efficiency of 65% at a wavelength of 900 nm. Suppose $0.5\mu\text{W}$ of optical power produces a multiplied photocurrent of $10\mu\text{A}$. What is the photo multiplication factor M.	4	4	3

24.	Explain how Pockels cell modulator works on Electro Optic Effect.	4	2	4
25.	Elaborate Optical MEMS Switches.	4	2	5
26.	Explain the various functions of data conversion unit	4	2	2
27.	In a Si Photodiode when a radiation of wavelength 700nm and generates a photocurrent of 56.6nA. What is the responsivity and quantum efficiency of the photodiode.	4	3	3

Part - C (5 × 12 Marks = 60 Marks)

Answer All Questions

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28.	a.From the wave equations for step-index fibers arrive at the boundary conditions for bounded modes. (OR) b.(i) Elaborate material and waveguide dispersion with necessary equations. [8 Marks] (ii) An LED operating at 850nm has a spectral width of 55nm and launches the power in 1Km fiber. What is the pulse spreading due to material dispersion? Given $(d^2n)/(d\lambda^2)=4 \times 10^{-2} \mu\text{m}^{-2}$. [4 Marks]	12	3	1
29.	a.Derive the threshold lasing condition of a LASER diode. (OR) b.Explain the mechanism of electro luminescence with neat diagram and also explain about operation of ac electroluminescence device.	12	4	2
30.	a. Draw and explain the functional blocks of a receiver module. (OR) b. List the various noise sources in photodetector and elaborate them with suitable equation.	12	4	3
31.	a. Explain principle of acousto-optic effect and modulator based on acousto-optic effect with thin grating. (OR) b. Demonstrate an interferometer which operates on the principle of electro-optic effect and derive the expression for bias voltage at which the modulation index is unity.	12	4	4
32.	a. A type-I intensity-modulated analog fiber-optic link employs a laser transmitter which couples a mean optical power of 1 dBm into a multimode optical fiber cable. The cable exhibits an attenuation of 2.5 dB/km with splice losses estimated at 0.45 dB/km. A connector at the receiver end shows a loss of another 1 dB. The p-i-n photodiode receiver has a sensitivity of -27 dBm for a CNR of -50 dB with a modulation index of 0.45. A safety margin of 6 dB is required. The rise times of the ILD and p-i-n diode are 1.5 ns and 4.5 ns, respectively, and the intermodal and intramodal rise times of the fiber cable are 8 ns/km and 3 ns/km, respectively. (i) What is the maximum possible link length without repeaters? (ii) What is the maximum permitted 3-dB bandwidth of the system? (OR) b. With a neat block diagram explain the operational principle of Radio- Over- Fiber. Mention its key link parameters used for designing.	12	3	5

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